

Data Sheet May 2013

6A, 600V Hyperfast Diodes

The RHRD660S9A_F085 is hyperfast diodes with soft recovery characteristics (t_{rr} < 30ns). It has half the recovery time of ultrafast diodes and are silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49057.



Features

- · Avalanche Energy Rated
- Planar Construction
- · Qualified to AEC Q101
- RoHS Compliant

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- General Purpose

Ordering Information

PART NUMBER	PACKAGE	BRAND	
RHRD660S9A_F085	TO-252	RHR660	

Symbol Packaging



JEDEC STYLE TO-252

CATHODE (FLANGE)

ANODE

DUDDEGGEO A EGGE

Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

	RHRD66059A_F085	UNITS
Peak Repetitive Reverse Voltage	600	V
Working Peak Reverse Voltage	600	V
DC Blocking VoltageV _R	600	V
Average Rectified Forward Current	6	Α
Repetitive Peak Surge Current	12	Α
Nonrepetitive Peak Surge Current	60	Α
Maximum Power Dissipation	50	W
Avalanche Energy (See Figures 10 and 11)	10	mJ
Operating and Storage Temperature	-55 to 175	oC
Maximum Lead Temperature for Soldering		
(Leads at 0.063 in. (1.6mm) from case for 10s)	300	οС
Package Body for 10s, see Tech Brief 334T _{PKG}	260	oC

LIMITO

RHRD660S9A F085

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 6A	-	-	2.1	V
	$I_F = 6A, T_C = 150^{\circ}C$	-	-	1.7	V
I _R	V _R = 600V	-	-	100	μΑ
	$V_R = 600V, T_C = 150^{\circ}C$	-	-	500	μΑ
t _{rr}	$I_F = 1A$, $dI_F/dt = 200A/\mu s$	-	-	30	ns
	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	-	35	ns
t _a	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	16	-	ns
t _b	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	8.5	-	ns
Q _{RR}	$I_F = 6A$, $dI_F/dt = 200A/\mu s$	-	45	-	nC
СЛ	V _R = 10V, I _F = 0A	-	20	-	pF
$R_{ heta JC}$		-	-	3	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of $t_a + t_b$.

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

 C_J = Junction capacitance.

 $R_{\theta,JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

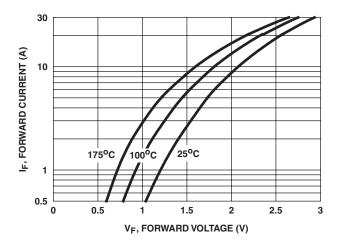


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

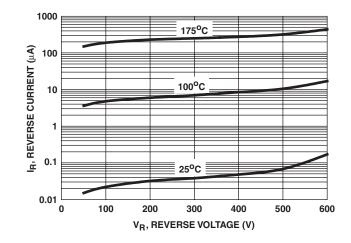


FIGURE 2. REVERSE CURRENT vs REVERSE

Typical Performance Curves (Continued)

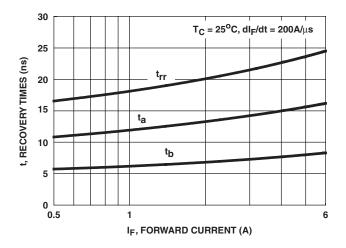


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

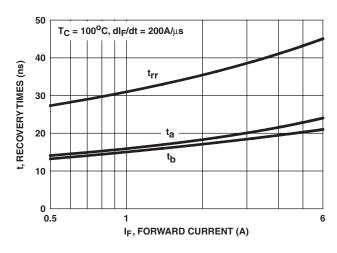


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

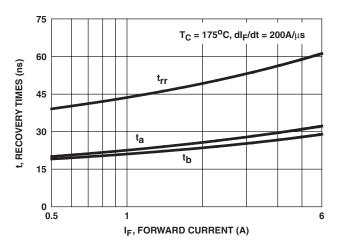


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

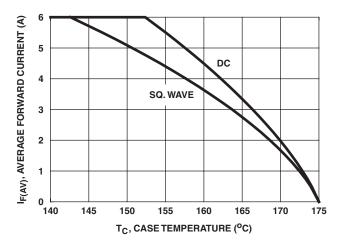


FIGURE 6. CURRENT DERATING CURVE

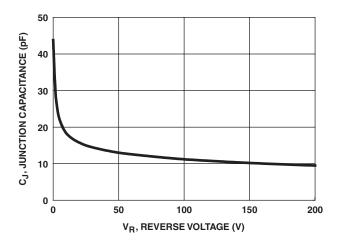


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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Test Circuits and Waveforms

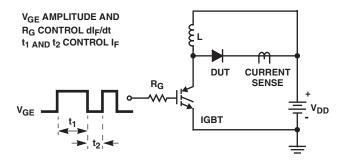


FIGURE 8. t_{rr} TEST CIRCUIT

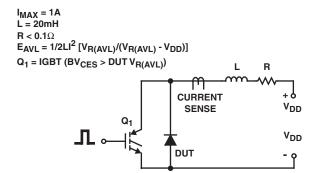


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

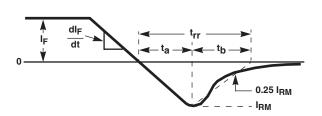


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

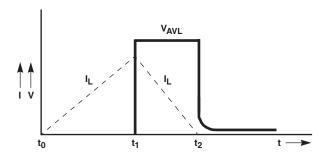


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS





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